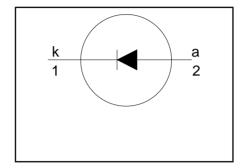
Damper diode ultra fast, high-voltage

BY559X-1500U

FEATURES

- · Low forward volt drop
- Low forward recovery voltage
- · Ultra Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

V _R = 1500 V
$V_F \le 1.5 \text{ V}$
$V_{fr} \leq 8 V$
$t_{rr} \le 130 \text{ ns}$
$I_{FWM} = 10 A$
$I_{FSM} \le 160 \text{ A}$

GENERAL DESCRIPTION

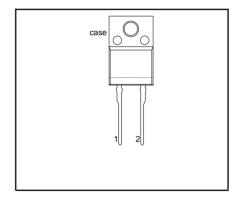
A double diffused rectifier diode in a plastic envelope, featuring ultra fast forward and reverse recovery and low forward voltage. The device is intended for use as a damper diode in horizontal deflection circuits of large screen monitors and workstations in applications up to 150kHz.

The BY559 series is supplied in the conventional leaded SOD59 and SOD113 packages.

PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	
case	isolated	

SOD113



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RRM}	Peak repetitive reverse voltage		-	1500	\ \
V_{RWM}	Crest working reverse voltage		-	1300	V
I _{FWM}	Peak working forward current	f = 120 kHz;	-	10	Α
I _{FRM}	Peak repetitive forward current	t = 100 μs	-	150	Α
I _{FSM}	Peak non-repetitive forward	t = 10 ms	-	160	Α
1 0	current	sinusoidal; T _i = 150 °C prior to			
		surge; with reapplied V _{RWM(max)}			
T _{stq}	Storage temperature	T T TOVINI(IIIAX)	-40	150	°C
Tj	Operating junction temperature		-	150	°C

ISOLATION LIMITING VALUE & CHARACTERISTIC

T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	-		2500	V
C _{isol}	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

Philips Semiconductors Product specification

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{\text{th } j\text{-hs}}$	Thermal resistance junction to heatsink	with heatsink compound	-	-	4.8	K/W
$R_{\text{th j-a}}$	Thermal resistance junction to ambient	in free air	-	55	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_{\rm F} = 6.5 \text{A}$	-	1.7	2.05	V
	_	$I_F = 6.5 \text{ A}; T_i = 125 ^{\circ}\text{C}$	-	1.2	1.5	V
I_R	Reverse current	$V_R = V_{RWMmax}$	-	-	0.5	mĄ
		$V_R = V_{RWMmax}$; $T_j = 125 ^{\circ}C$	-	-	2.0	mA

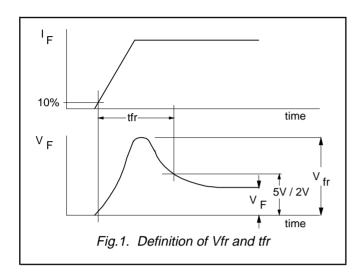
DYNAMIC CHARACTERISTICS

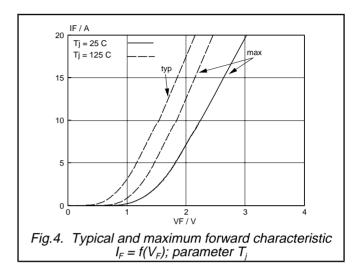
T_i = 25 °C unless otherwise stated

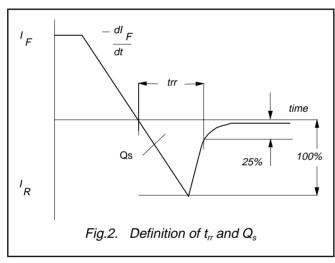
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$ \begin{array}{ c c } V_{fr} \\ t_{fr} \\ t_{rr} \\ Q_{s} \end{array} $	Forward recovery time Reverse recovery time	$\begin{array}{l} I_F = 6.5 \text{ A; } dI_F/dt = 50 \text{ A/}\mu\text{s} \\ I_F = 6.5 \text{ A; } dI_F/dt = 50 \text{ A/}\mu\text{s; } V_F = 5 \text{ V} \\ I_F = 1 \text{ A; } -dI_F/dt = 50 \text{ A/}\mu\text{s; } V_R \geq 30 \text{ V} \\ I_F = 2 \text{ A; } -dI_F/dt = 20 \text{ A/}\mu\text{s; } V_R \geq 30 \text{ V} \end{array}$	-	6 130 100 0.2	8 180 130 0.3	V ns ns μC

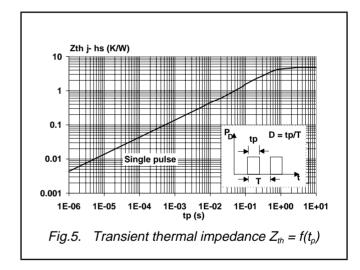
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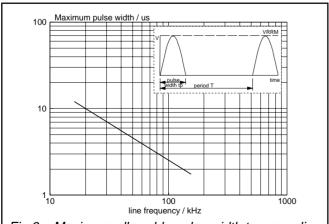
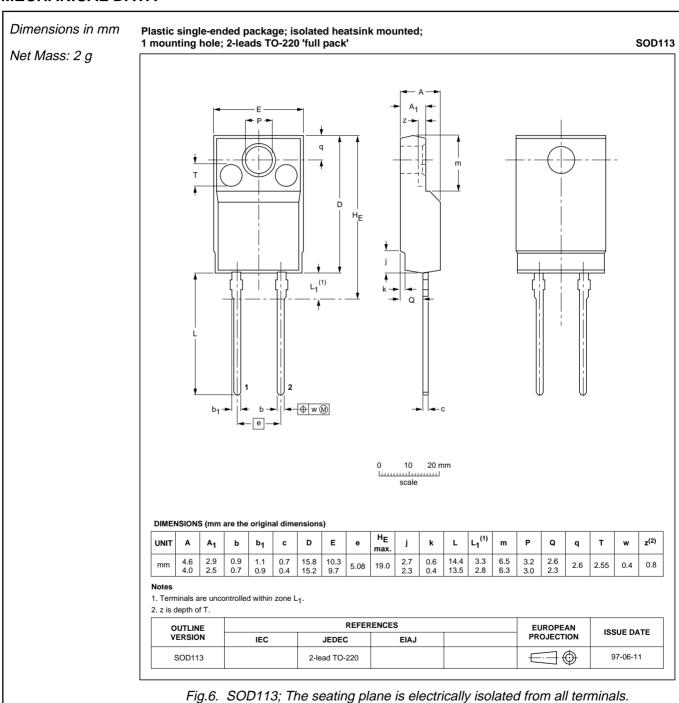


Fig.3. Maximum allowable pulse width $t_{\rm p}$ versus line frequency; Basic horizontal deflection circuit.

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MECHANICAL DATA



Notes

- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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